NSN 5962-01-123-7994

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Body Length: 1.290 inches **Body Width:** Between 0.500 inches and 0.610 inches **Body Height:** Between 0.150 inches and 0.210 inches **Maximum Power Dissipation Rating:** 575.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** 5840-01-105-4656 81755 **Features Provided:** Burn in and monolithic and bipolar and programmable **Inclosure Material:** Ceramic Inclosure Configuration: Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 8 input **Case Outline Source And Designator:** D-3 mil-m-38510 **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** -1.5 volts power source and 5.5 volts power source **Time Rating Per Chacteristic:** 140.00 nanoseconds propagation delay time, low to high level output and 140.00 nanoseconds propagation delay time, high to low level output Memory Device Type: Rom **Terminal Type And Quantity:** 24 printed circuit Shelf Life: N/a Unit Of Measure: ---**Demilitarization:** Yes - demil/mli

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